

- Murray R B and Williams R H 1974 *Phil. Mag.* **29** 473-92
- Paul W 1968 *Proc. 9th Int. Conf. on Physics of Semiconductors, Moscow* (Leningrad: Nauka)
- Pitt G D 1968 *J. Phys. E: Sci. Instrum.* **1** 915-7
- Pitt G D and Gunn D A 1970 *High Temp.-High Press.* **2** 547-52
- Revolinsky E and Beerntsen D 1964 *J. Appl. Phys.* **35** 2086-9
- Shepherd F R and Williams P M 1974 *J. Phys. C: Solid St. Phys.* **7**, 4416-40
- Shepherd F R, Williams P M, Young D A and Scruby C B 1974 *Proc. 12th Int. Conf. on Physics of Semiconductors, Stuttgart* ed M Pilkuhn (Stuttgart: Teubner-Verlag)
- Smith R A 1959 *Semiconductors* (London: Cambridge UP)
- Title R S and Shafer M W 1972 *Phys. Rev. Lett.* **28** 808-10
- 1973 *Phys. Rev.* **B8** 615-20
- van der Pauw L J 1958 *Philips Res. Rep.* **13** 1-9
- Wertheim G K, Di Salvo F J and Buchanan D N E 1973 *Solid St. Commun.* **13** 1225-8
- Williams P M and Shepherd F R 1973 *J. Phys. C: Solid St. Phys.* **6** L36-40
- Williams R H 1973 *J. Phys. C: Solid St. Phys.* **6** L32-5
- Wilson J A and Yoffe A D 1969 *Adv. Phys.* **18** 193-335
- Wood K and Pendry J B 1973 *Phys. Rev. Lett.* **31** 1400-3
- Yoffe A D 1973 *Festkörperprobleme* **13** ed H J Queisser (Vieweg: Braunschweig) pp 1-29
- 1974 *Proc. 12th Int. Conf. on Physics of Semiconductors* ed M Pilkuhn (Stuttgart: Teubner)